

# Electron Beam Dynamics Simulations for the Low Emittance Gun

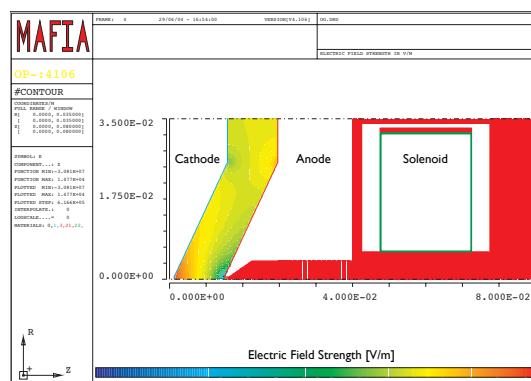
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## 100 keV Test Stand

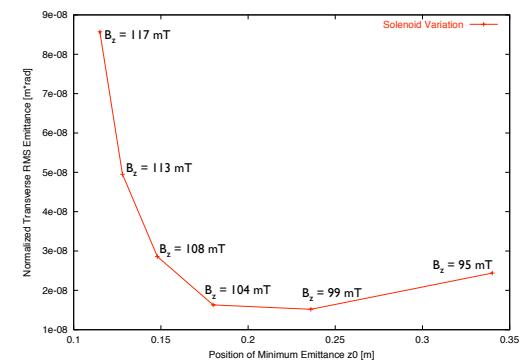
### Input Parameters

- Cathode Potential: -100kV
  - Active Emitter Radius:  $r_{act} = 100\mu\text{m}$
  - Pulse: Gaussian, cut-off at  $\pm 3\sigma_t$ ,  $\sigma_t = 20\text{ps}$ ,  $Q = 5 \cdot 10^{-12}\text{C}$  ( $i = 100\text{mA}$ )
  - Initial Energy:  $\gamma_0 = 1.0001$ , initial divergence is set to zero
  - Iris:  $r_{iris} = 500\mu\text{m}$
  - Tracked Macro-Particles:  $N = 20000$
  - Tracked Path:  $1\text{mm} < z < 342\text{ mm}$  (from cathode surface to end of drift)
  - Solenoid:  $7\text{A/mm}^2$  capable of delivering  $B_z = 200\text{mT}$  on axis
- Peak electric field strength below 19MV/m  
 → Norm. transv. emittance at gun exit <  $2 \cdot 10^{-8} \text{ m} \cdot \text{rad}$

### Test Stand Gun Design



### Simulated Emittance (MAFIA)



### Projected Emittance vs. Slice Emittance

**Projected Emittance**  
 (property of one entire bunch)  
 $\varepsilon = \sqrt{\langle r^2 \rangle \langle p_r^2 \rangle - \langle r p_r \rangle^2} \simeq \gamma \beta \sqrt{\langle r^2 \rangle \langle r'^2 \rangle - \langle r r' \rangle^2}$

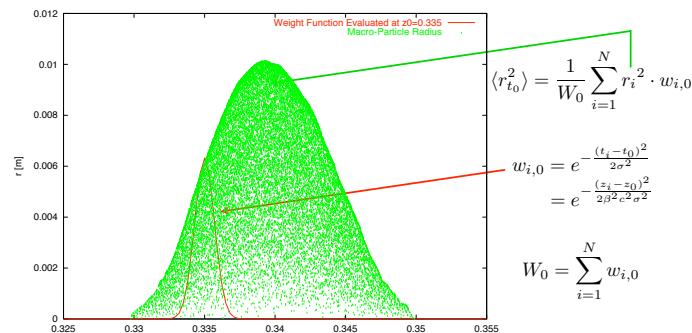
**Slice Emittance**  
 (depends on the location  $z_0$  of the slice within the bunch and the width  $\sigma_t$  of the slice)  
 $\varepsilon_{t_0} = \gamma \beta \sqrt{\langle r_{t_0}^2 \rangle \langle r'^{t_0}_0 \rangle - \langle r_{t_0} r'^{t_0}_0 \rangle^2}$

$$\langle r_{t_0}^2 \rangle = \frac{1}{W_0} \sum_{i=1}^N r_i^2 \cdot w_{i,0}$$

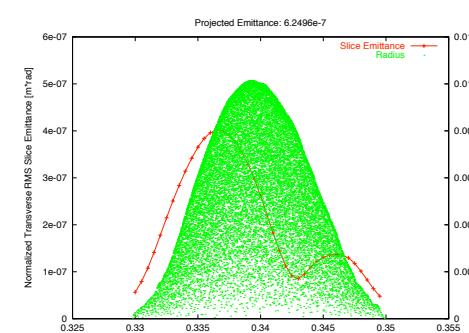
$$w_{i,0} = e^{-\frac{(t_i - t_0)^2}{2\sigma_t^2}} = e^{-\frac{(z_i - z_0)^2}{2\beta^2 c^2 \sigma_t^2}}$$

$$W_0 = \sum_{i=1}^N w_{i,0}$$

### Sampling the Bunch



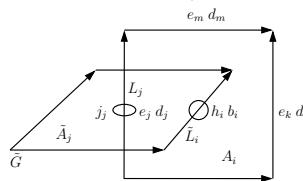
### Slice Emittance Calculation



## Simulations with Capone

### Dynamic Field Solver

- Finite Integration Technique (FIT)
- Discretization of volume on two rectilinear grids:  $G, \tilde{G}$
- Cells with volumes  $V_i, \tilde{V}_i$ , cell faces  $A_i, \tilde{A}_i$ , and grid lines  $L_i, \tilde{L}_i$
- Store integrated field components  $e_j = \int_{L_j} \vec{E} \cdot d\vec{s}$
- Discrete curl operators  $C, \tilde{C}$  and divergence operators  $S, \tilde{S}$
- Discrete material operators  $D_\epsilon, D_\mu$



### Discrete Maxwell's Equations

$$C \ e = -\frac{\partial b}{\partial t}$$

$$\tilde{C} \ h = \frac{\partial d}{\partial t} + j$$

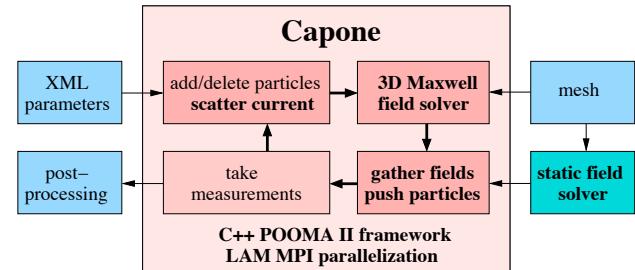
$$\tilde{S} \ d = q$$

$$S \ b = 0$$

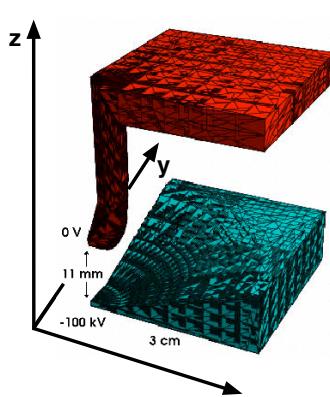
$$d = D_\epsilon e$$

$$b = D_\mu h$$

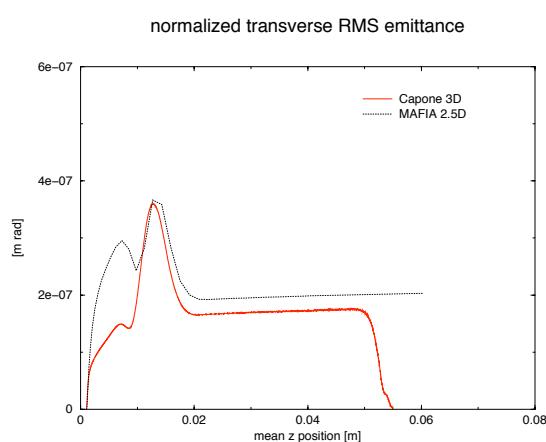
### Program Structure



### Simulated Gun Geometry



### Comparison: Capone vs. MAFIA



### Slice Emittance Calculations

